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Docket No.: 2336-255

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

Seung Wan CHAE

U.S. Patent Application No. 10/812,015

Filed: March 30, 2004

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Confirmation No. 2799
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Group Art Unit: 2811
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Examiner: Hung K VuFor: GALLIUM NITRIDE (GaN)-BASED SEMICONDUCTOR LIGHT EMITTING DIODE
AND METHOD FOR MANUFACTURING THE SAMEAMENDMENTCOMMISSIONER FOR PATENTS
P.O. Box 1450
Alexandria VA 22313-1450

Sir:

The following amendments and remarks are submitted in response to the Official Action dated *August 25, 2005*.

CERTIFICATION OF FACSIMILE TRANSMISSION
I HEREBY CERTIFY THAT THIS PAPER IS BEING FACSIMILE TRANSMITTED
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Kindra Bryant

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